

## HF/VHF/UHF RF power N-channel MOSFET

Datasheet - production data

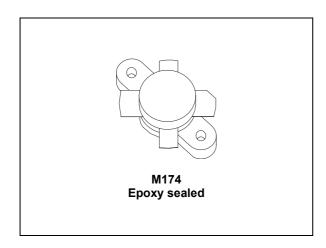
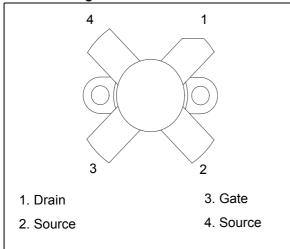


Figure 1. Pin connection



#### **Features**

- Improved ruggedness V<sub>(BR)DSS</sub> > 200 V
- Excellent thermal stability
- · 20:1 all phases load mismatch capability
- P<sub>OUT</sub> = 150 W min. with 14.8 dB gain @ 175 MHz
- In compliance with the 2002/95/EC European directive

#### **Description**

The SD4931 is an N-channel MOS field-effect RF power transistor. It is intended for use in 50 V DC large signal applications up to 250 MHz.

Table 1. Device summary

| Order code | Marking               | Base qty. | Package | Packaging <sup>(1)</sup> |
|------------|-----------------------|-----------|---------|--------------------------|
| SD4931     | SD4931 <sup>(1)</sup> | 25 pcs    | M174    | Plastic tray             |

<sup>1.</sup> For more details please refer to Chapter 5: Marking, packing and shipping specifications.

Contents SD4931

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SD4931 Electrical data

## 1 Electrical data

## 1.1 Maximum ratings

Table 2. Absolute maximum ratings ( $T_{CASE} = 25 \, ^{\circ}C$ )

| Symbol               | Parameter                                     | Value       | Unit |
|----------------------|---|-------------|------|
| V <sub>(BR)DSS</sub> | Drain source voltage                          | 200         | V    |
| $V_{DGR}$            | Drain-gate voltage ( $R_{GS}$ = 1 $M\Omega$ ) | 200         | V    |
| V <sub>GS</sub>      | Gate-source voltage                           | ±20         | ٧    |
| I <sub>D</sub>       | Drain current                                 | 20          | Α    |
| P <sub>DISS</sub>    | Power dissipation                             | 389         | W    |
| T <sub>J</sub>       | Max. operating junction temperature           | 200         | °C   |
| T <sub>STG</sub>     | Storage temperature                           | -65 to +150 | °C   |

#### 1.2 Thermal data

Table 3. Thermal data

| Symbol     | Parameter                          | Value | Unit |
|------------|------------------------------------|-------|------|
| $R_{thJC}$ | Junction - case thermal resistance | 0.45  | °C/W |

Electrical characteristics SD4931

## 2 Electrical characteristics

 $T_{CASE}$  = +25 °C

#### 2.1 Static

Table 4. Static

| Symbol               |                        | Test conditions          | Min       | Тур | Max | Unit |    |
|----------------------|------------------------|--------------------------|-----------|-----|-----|------|----|
| V <sub>(BR)DSS</sub> | $V_{GS} = 0 V$         | I <sub>DS</sub> = 100 mA |           | 200 |     |      | V  |
| I <sub>DSS</sub>     | $V_{GS} = 0 V$         | V <sub>DS</sub> = 100 V  |           |     |     | 1    | mA |
| I <sub>GSS</sub>     | V <sub>GS</sub> = 20 V | $V_{DS} = 0 V$           |           |     |     | 250  | nA |
| $V_{GS(Q)}$          | V <sub>DS</sub> = 10 V | I <sub>D</sub> = 250 mA  |           | 1.5 | 2.5 | 4.0  | V  |
| V <sub>DS(ON)</sub>  | V <sub>GS</sub> = 10 V | I <sub>D</sub> = 10 A    |           |     | 3.5 | 5.0  | V  |
| G <sub>FS</sub>      | V <sub>DS</sub> = 10 V | I <sub>D</sub> = 2.5 A   |           | 2.5 | 4.0 |      | S  |
| C <sub>ISS</sub>     | V <sub>GS</sub> = 0 V  | V <sub>DS</sub> = 50 V   | f = 1 MHz |     | 500 |      | pF |
| Coss                 | V <sub>GS</sub> = 0 V  | V <sub>DS</sub> = 50 V   | f = 1 MHz |     | 200 |      | pF |
| CRSS                 | V <sub>GS</sub> = 0 V  | V <sub>DS</sub> = 50 V   | f = 1 MHz |     | 8   |      | pF |

## 2.2 Dynamic

Table 5. Dynamic

| Symbol           | Test conditions   | Min  | Тур  | Max | Unit |
|------------------|---|------|------|-----|------|
| P <sub>1dB</sub> | $V_{DD} = 50 \text{ V}$ $I_{DQ} = 250 \text{ mA}$ $f = 175 \text{ MHz}$                         | 150  | 175  |     | W    |
| G <sub>PS</sub>  | $V_{DD} = 50 \text{ V } I_{DQ} = 250 \text{ mA} P_{OUT} = 150 \text{ W } f = 175 \text{ MHz}$   | 13   | 14.8 |     | dB   |
| n <sub>D</sub>   | $V_{DD} = 50 \text{ V}$ $I_{DQ} = 250 \text{ mA}$ $P_{OUT} = 150 \text{ W f} = 175 \text{ MHz}$ |      | 56   |     | %    |
| Load<br>mismatch | $V_{DD}$ = 50 V $I_{DQ}$ = 250 mA $P_{OUT}$ = 150 W f = 175 MHz All phase angles                | 10:1 | 20:1 |     | VSWR |

# 3 Typical performance

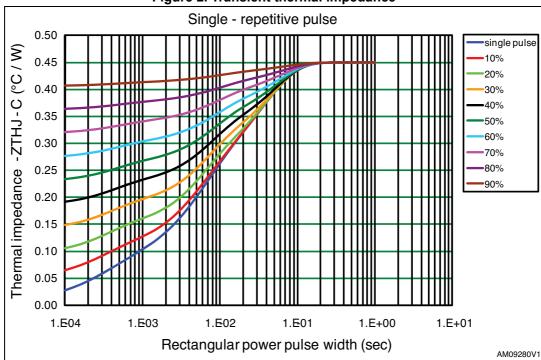


Figure 2. Transient thermal impedance

Typical performance SD4931

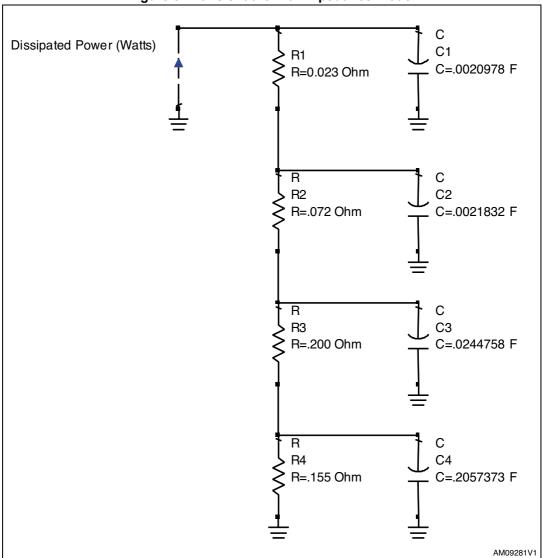


Figure 3. Transient thermal impedance model



SD4931 Typical performance

-Pgain Efficiency Pgain (dB) 14 Output Power (W)

Figure 4. Power gain and efficiency vs output power\_Vdd = 50 V, Idq = 250 mA, Freq = 175 MHz

Table 6. Vgs sort (@250 mA)

| Marking | Min. | Max. |
|---------|------|------|
| DD      | 1.5  | 1.6  |
| EE      | 1.6  | 1.7  |
| FF      | 1.7  | 1.8  |
| A       | 1.8  | 1.9  |
| В       | 1.9  | 2    |
| С       | 2    | 2.1  |
| D       | 2.1  | 2.2  |
| E       | 2.2  | 2.3  |
| F       | 2.3  | 2.4  |
| G       | 2.4  | 2.5  |
| Н       | 2.5  | 2.6  |
| I       | 2.6  | 2.7  |
| J       | 2.7  | 2.8  |
| К       | 2.8  | 2.9  |
| L       | 2.9  | 3    |
| M       | 3    | 3.1  |
| N       | 3.1  | 3.2  |
| 0       | 3.2  | 3.3  |
| Р       | 3.3  | 3.4  |
| Q       | 3.4  | 3.5  |

Typical performance SD4931

Table 6. Vgs sort (@250 mA) (continued)

| Marking | Min. | Max. |
|---------|------|------|
| R       | 3.5  | 3.6  |
| S       | 3.6  | 3.7  |
| Т       | 3.7  | 3.8  |
| U       | 3.8  | 3.9  |
| V       | 3.9  | 4    |

## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 7. M174 (0.500 DIA 4/L N/HERM W/FLG) mechanical data

| Dim  |       | mm.  |       |       | Inch  |       |
|------|-------|------|-------|-------|-------|-------|
| Dim. | Min   | Тур  | Max   | Min   | Тур   | Max   |
| Α    | 5.56  |      | 5.584 | 0.219 |       | 0.230 |
| В    |       | 3.18 |       |       | 0.125 |       |
| С    | 6.22  |      | 6.48  | 0.245 |       | 0.255 |
| D    | 18.28 |      | 18.54 | 0.720 |       | 0.730 |
| E    |       | 3.18 |       |       | 0.125 |       |
| F    | 24.64 |      | 24.89 | 0.970 |       | 0.980 |
| G    | 12.57 |      | 12.83 | 0.495 |       | 0.505 |
| Н    | 0.08  |      | 0.18  | 0.003 |       | 0.007 |
| I    | 2.11  |      | 3.00  | 0.083 |       | 0.118 |
| J    | 3.81  |      | 4.45  | 0.150 |       | 0.175 |
| К    |       |      | 7.11  |       |       | 0.280 |
| L    | 25.53 |      | 26.67 | 1.005 |       | 1.050 |
| М    | 3.05  |      | 3.30  | 0.120 |       | 0.130 |



Figure 5. Package dimensions



# 5 Marking, packing and shipping specifications

Table 8. Packing and shipping specifications

| Order code | Packaging    | Pcs per<br>tray | Dry pack<br>humidity | Vgs sort  | Lot code  |
|------------|--------------|-----------------|----------------------|-----------|-----------|
| SD4931     | Plastic tray | 25              | < 10%                | Not mixed | Not mixed |

Figure 6. Marking layout

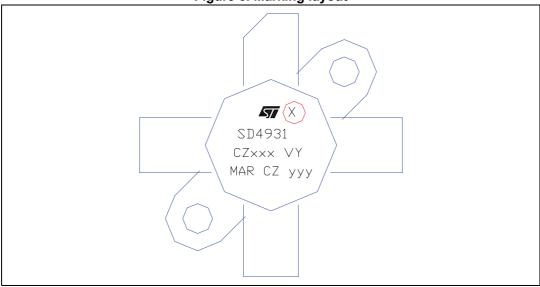


Table 9. Marking specifications

| Symbol | Description                    |
|--------|--------------------------------|
| X      | V <sub>GS</sub> sort           |
| CZ     | Assembly plant                 |
| XXX    | Last 3 digits of diffusion lot |
| VY     | Diffusion plant                |
| MAR    | Country of origin              |
| CZ     | Test and finishing plant       |
| у      | Assembly year                  |
| уу     | Assembly week                  |



Revision history SD4931

# 6 Revision history

**Table 10. Document revision history** 

| Date        | Revision | Changes  |
|-------------|----------|--|
| 17-Mar-2008 | 1        | Initial release.   |
| 14-Jan-2010 | 2        | Updated test conditions in <i>Table 5: Dynamic</i> .   |
| 23-May-2011 | 3        | Inserted Figure 2: Transient thermal impedance, Figure 3: Transient thermal impedance model and Section 5: Marking, packing and shipping specifications.   |
| 10-Jun-2013 | 4        | <ul> <li>Modified document title to "HF/VHF/UHF RF power N-channel MOSFET"</li> <li>Corrected error in V<sub>GS(Q)</sub> symbol and test conditions in <i>Table 4:</i> Static.</li> <li>Minor text edits.</li> </ul> |

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